Application No.: 10/582,983 Docket No.: 0965-0472PUS1

Reply to Office Action of January 4, 2008

AMENDMENTS TO THE CLAIMS

1. (Currently Amended) A plasma processing apparatus, comprising:

gas supply means for supplying a gas including a reactant gas to an interior of a chamber;

pressure control means for controlling an internal pressure of the chamber;

plasma generation means for generating a plasma of the gas in the interior of the

chamber;

a susceptor, installed in a lower portion of the interior of the chamber, for supporting a

substrate to be processed;

a wall surface protecting member, formed in a cylindrical form and provided in the

interior of the chamber, for preventing adhesion of a plasma processing-associated product onto

an inner wall surface of the chamber.

wherein the chamber includes a chamber step portion, provided to the inner wall surface

of the chamber, for supporting the wall surface protecting member from below to cover the inner

wall surface of the chamber located above the susceptor,

wherein the wall surface protecting member has a plurality of projections, provided on an

outer wall surface and in a lower end portion of the wall surface protecting member, for

contacting, by point contact, the inner wall surface of the chamber and the chamber step portion,

wherein the plurality of projections provided in the lower end portion of the wall surface

protecting member extends along an axial direction of the wall surface protecting member, and

wherein the wall surface protecting member is supported in the chamber by the point

contact.

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(Canceled)

3. (Canceled)

- (Currently Amended) The plasma processing apparatus according to <u>claim 1 or</u>
 <u>13elaim-1</u>, wherein the wall surface protecting member is made of a ceramic.
- (Currently Amended) The plasma processing apparatus according to <u>claim 1 or</u>
 13elaim 1, wherein the wall surface protecting member is made of a metal.
- (Previously Presented) The plasma processing apparatus according to claim 5, wherein the metal is aluminum.
- (Previously Presented) The plasma processing apparatus according to claim 5, wherein the wall surface protecting member has a surface oxidized.
- (Currently Amended) The plasma processing apparatus according to <u>claim 1 or 13elaim 1</u>, wherein the wall surface protecting member has a surface roughened.
- (Currently Amended) The plasma processing apparatus according to <u>claim 1 or</u>
 13elaim-1, wherein the gas supply means is installed while passing through a hole provided in the wall surface protecting member.

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10. (Canceled)

(Currently Amended) The plasma processing apparatus according to <u>claim 1 or</u>

heating means for heating a wall surface of the chamber.

(Previously Presented) The plasma processing apparatus according to claim 11,
 wherein the heating means heats the wall surface of the chamber to 100°C or higher.

13. (New) The plasma processing apparatus according to claim 1, wherein the plurality of projections provided on the outer wall surface of the wall surface protecting member is provided at a lower portion of the wall surface protecting member.